L Number	Hits	Search Text	I/B	Time stamp
1	79	selectiv\$4 near3 etch\$4 near4 (epitax\$4) same nitride	USPAT; US-PGPUB; EFO; JPO; DEFWENT;	2003/06 04 39:19
2	4.4	gehrke.in. or linthicum.in.) and gallium adj nitride	IBM_TOB USFAT: US-PGPUB; EFG; GFG; DERWENT; IBM_TOB	2003106104 09:14
	2	(layer\$3 same substrate same (gan or gallium adj nitride or sapphire or zinc adj oxide or zno or silicon adj carbide or silicon or si or sic) and two near2 sid\$3 same deposit\$4) and 117 84-109.ccls.	USFAT; US-PGFUE; EPG; UFG; DEPWENT; IEM_TDB	3000 12723 16:0)
-	15	two near1 layer\$3 near3 substrate near4 (gan or gallium adj nitride or sapphire or mind adj oxide or zno or silicon adj darbide or silicon or si or sic) and	USFAT; US-PGFUB; EFC; JFC; DEFWENT;	3600×12/23 16:3:
_	38	117:\$4.ccls. multi\$11ayer\$3 near3 substrate and 117:\$4.ccls. and (remov\$3 near2 substrate)	IEM_THE USIAT; US-PGPUB; EPG; JEG; IEPWEHT;	2001 12 23 16:21
-	2	two nearl sid\$3 near4 deposit\$4 and 117,\$4.ccls.	IBM_TPB USFAT; US-PGPUB; EPO; JPO; PEPWENT; IBM_TPB	2102 12×23 16:49
_	96	double near2 sid\$2 near2 (epitax\$4 or deposit\$4)	USFAT; US-PGFUE; EPO; JFO; DEPWENT; IBM TUE	2002/12/31 10:27
-	16	heat\$4 near10 lamp same cvd same (reactor or chamber) same inside and epitax\$4	USFAT; US-PGPUE; EPO; JPO; LEPWENT; IBM TUB	2003/06/02 16:07
_	13	heat\$4 near10 lamp near10 (insid\$4 or intern\$4) same ovd	USFAT; US-PGFUP; EPO; JFO; DEPWENT; IBM TIB	2003/06,02 [16:1]
_	23	heat\$4 near10 lamp same cvd same (reactor or chamber) same direct\$4 and epitax\$4	USPAT; US-PGFUB; EPO; JPO; DEPWENT; IBM TUB	2003/06,03 03:37
	4	layered near5 substrate same bow\$4	USPAT; US-PGFUP; EPO; JPO; DEPWENT; IBM TDB	2003/06/03 09:40
_	33	layered near5 substrate same sapphire same nitride	USFAT; US-PGPUB; EPC; JPO; DEPWENT; IBM TUB	2003/06/03
_	5 4	<pre>(multi\$1layer\$1) near2 substrate same sapphire</pre>	USFAT; US-PGPUB; EPG; JPG; DEFWENT; IBM TDB	2003/06/03 10:21

-	É	(multi\$llayer\$1) near2 substrate same (warp\$4 or pow\$4) same nitride	USPAT; US-PGPUB; EPO; JPO;	2003 06,03 10:14
			IEEWENT; IBM_TDB	
_	3	(multi\$1layer\$1) near2 substrate same (warp\$4 or bow\$4) and epitax\$4	USFAT; US-PGPUE; EPD; JFD;	2003/06/03 10:24
			IERWENT; IBM_TIB	
_	38	rotat\$4 near4 substrate near4 stationar\$4 same uniform\$4	USPAT; US-PGPUB; EPO; UPO;	2003/06/03 10:53
	34	rotat\$4 near4 substrate near4 stationar\$4	IEFWENT; IBM_TDP USFAT;	2003706,103
		and (CVD)	US-PGFUB; EPO; JEO; LEFWELT;	11:45
			IBM_TLE	0.000 0.07.5
_	29	remov\$4 near3 substrate same epitax\$4 same polish\$4 same nitride	USFAT; US-PGFUB; EPO; UFO;	2003 06/03
			DEFWENT: IBM TUE	
_	g _j	remov\$4 near3 substrate same polish\$4 and 117/915.ccls.	USFĀT; US-PGPUB;	2003 06/03 11:53
			EPO; JEO; DEPWENT; IBM TIE	
-	30	electrochemical near3 polish\$4 same mechanical near3 polish\$4 same substrate	USFAT; US-PGFUB; EPC; JFO;	2003-06,103 13:28
			DEFWENT;	
-	18	layered near3 substrate and "iii-v" and 117/\$4.ctls.	IBM_TIB USFAT; US-PGFUE;	2003/06/03 13:45
			EPO; JPO; DEPWENT; IBM TUB	
	21	layered near2 substrate same warp\$3	USFAT; US-PGFUB;	2003 06/03 13:41
			EPO; JFO; DEFWENT; IBM TOB	
_	78	layered near5 substrate and 117/\$4.ccls.	USPAT; US-PGFUE;	2003 06/03 14:15
			EPO; JEO; DEPWENT; IBM_TDB	
-	25	(Gan or gallium adj nitride) near4 thick near6 epitax\$4 same sapphire near2 substrate	USPAT; US-PGPUB; EPO; JPO;	2003/06/03 15:23
			DERWENT;	
_	33	pattern\$4 near4 (GaN or gallium near2 nitride) and 117/\$4.ccls.	USFAT; US-PGFUE;	2003 06/03 16:19
			EPO; JPO; DEFWENT; IBM TDB	
_	99	pattern\$4 near4 (GaN or gallium near2 nitride) and 257/\$4.ccls.	USFAT; US-PGFUE;	2003/06/03 16:21
			EPO; JPO; LEPWENT;	
_	31	selectiv\$4 near3 etch\$4 near4 (GaN or	IBM_TDB USFAT;	2003/06/03
		gallium near2 nitride) and 257/\$4.ccls.	US-PGFUP; EPO; JPO; DEFWENT;	15:24
			IBM TIB	

_	10	selectiv\$4 near3 etch\$4 near4 (epi	itax\$4 USPAT;	2003/06/03
		near5 nitride:	US-PGPUB;	16:26
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
_	1 11	selectiv\$4 near3 etch\$4 near4 (epi	ltax\$4: USFAT;	2003/06/04
		same "lli-v"	US-PGPUB;	09:16
			EPO; JPO;	
			DERWENT;	
			IEM TDB	